## NSN 5961-00-905-1104

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.330 inches and 0.505 inches
Mounting Facility Quantity:
1
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 0.544 inches and 0.562 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
3.0 gate trigger voltage, dc and 2.0 on-state voltage, dc
Current Rating Per Characteristic:
16.00 amperes forward current, total rms nanoamperes and 150.00 amperes forward current, total rms watts
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Specification Data:
80131-release3681 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0